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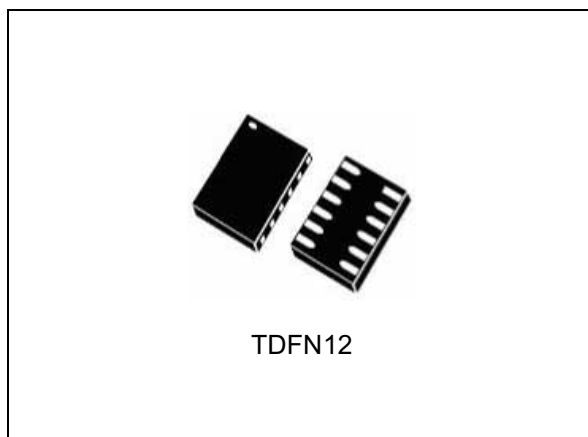
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## Smart push-button on/off controller with Smart Reset™ and power-on lockout

Datasheet - production data



- Debounced  $\overline{\text{PB}}$  and  $\overline{\text{SR}}$  inputs
- $\overline{\text{PB}}$  and  $\overline{\text{SR}}$  ESD inputs withstand voltage up to  $\pm 15$  kV (air discharge)  $\pm 8$  kV (contact discharge)
- Active high or active low enable output option ( $\overline{\text{EN}}$  or  $\text{EN}$ ) provides control of MOSFET, DC-DC converter, regulator, etc.
- Secure startup, interrupt, Smart Reset™ or power-down driven by push-button
- Precise 1.5 V voltage reference with 1% accuracy
- Industrial operating temperature  $-40$  to  $+85$  °C
- Available in TDFN12 2 x 3 mm package

### Features

- Operating voltage 1.6 V to 5.5 V
- Low standby current of 0.6  $\mu\text{A}$
- Adjustable Smart Reset™ assertion delay time driven by external  $\text{C}_{\text{SRD}}$
- Power-up duration determined primarily by push-button press (STM6600) or by fixed time period,  $t_{\text{ON\_BLANK}}$  (STM6601)

### Applications

- Portable devices
- Terminals
- Audio and video players
- Cell phones and smart phones
- PDAs, palmtops, organizers

Table 1. Device summary

Device	$\overline{\text{RST}}$	$\text{C}_{\text{SRD}}$	$\overline{\text{PB}} / \overline{\text{SR}}$	$\text{EN}$ or $\overline{\text{EN}}$	$\overline{\text{INT}}$	Startup process
STM6600	open drain <sup>(1)</sup>	✓	✓	Push-pull	Open drain <sup>(1)</sup>	$\overline{\text{PB}}$ must be held low until the $\text{PS}_{\text{HOLD}}$ <sup>(2)</sup> confirmation
STM6601	open drain <sup>(1)</sup>	✓	✓	Push-pull	Open drain <sup>(1)</sup>	$\text{PB}$ can be released before the $\text{PS}_{\text{HOLD}}$ <sup>(2)</sup> confirmation

1. External pull-up resistor needs to be connected to open drain outputs.

2. For a successful startup, the  $\text{PS}_{\text{HOLD}}$  (power supply hold) needs to be pulled high within specific time,  $t_{\text{ON\_BLANK}}$ .

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## 1 Description

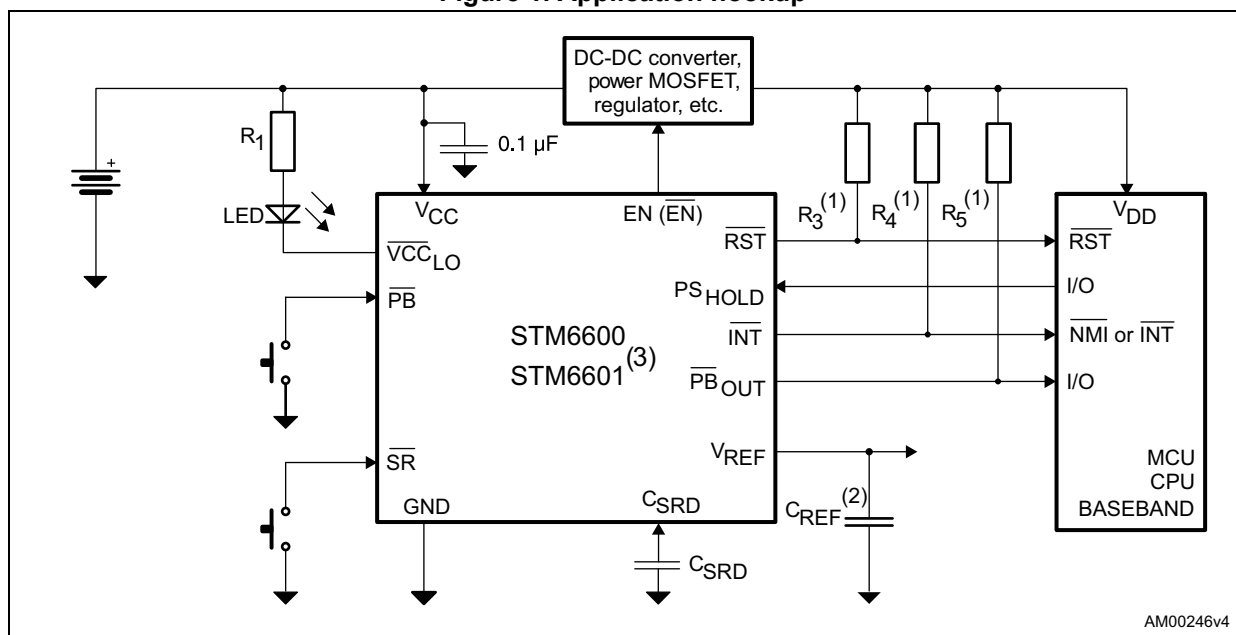
The STM6600-01 devices monitor the state of connected push-button(s) as well as sufficient supply voltage. An enable output controls power for the application through the MOSFET transistor, DC-DC converter, regulator, etc. If the supply voltage is above a precise voltage threshold, the enable output can be asserted by a simple press of the button. Factory-selectable supply voltage thresholds are determined by highly accurate and temperature-compensated references. An interrupt is asserted by pressing the push-button during normal operation and can be used to request a system power-down. The interrupt is also asserted if undervoltage is detected. By a long push of one button ( $\overline{\text{PB}}$ ) or two buttons ( $\overline{\text{PB}}$  and  $\overline{\text{SR}}$ ) either a reset is asserted or power for the application is disabled depending on the option used.

The device also offers additional features such as precise 1.5 V voltage reference with very tight accuracy of 1%, separate output indicating undervoltage detection and separate output for distinguishing between interrupt by push-button or undervoltage.

The device consumes very low current of 6  $\mu\text{A}$  during normal operation and only 0.6  $\mu\text{A}$  current during standby.

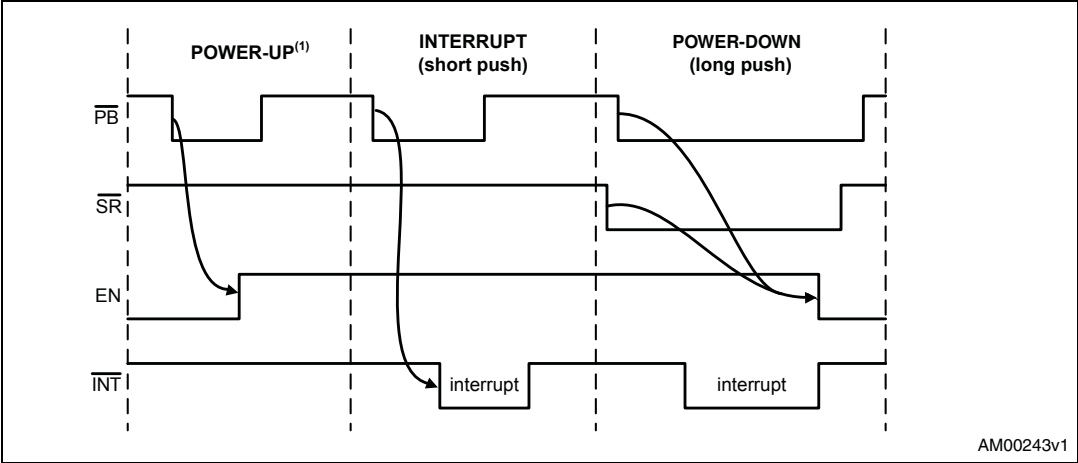
The STM6600-01 is available in the TDFN12 package and is offered in several options among features such as selectable threshold, hysteresis, timeouts, output types, etc.

### Figure 1. Application hookup



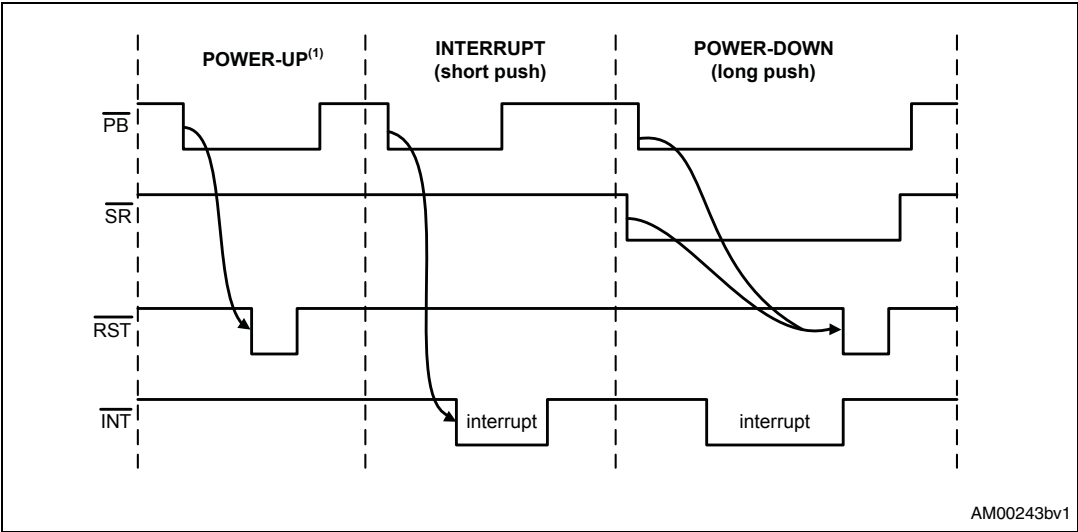
1. A resistor is required for open drain output type only. A 10 kΩ pull-up is sufficient in most applications.
2. Capacitor  $C_{REF}$  is mandatory on  $V_{REF}$  output (even if  $V_{REF}$  is not used). Capacitor value of 1 μF is recommended.
3. For the STM6601 the processor has to confirm the proper power-on during the fixed time period,  $t_{ON\_BLANK}$ . This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.

Figure 2. Basic functionality (option with enable deassertion after long push)



1. For power-up the battery voltage has to be above  $V_{TH+}$  threshold.

Figure 3. Basic functionality (option with  $\overline{RST}$  assertion after long push)



1. For power-up the battery voltage has to be above  $V_{TH+}$  threshold.

Figure 4. Logic diagram

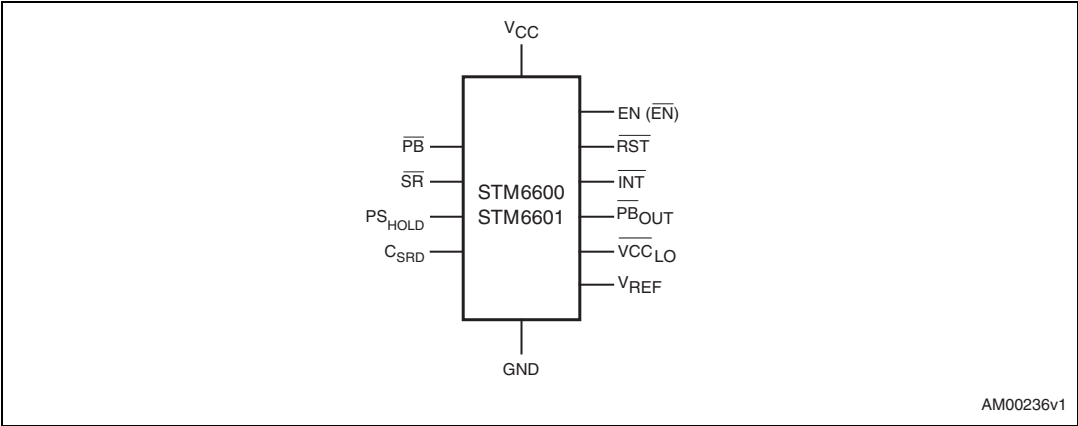


Table 2. Pin descriptions

Pin number	Symbol	Function
1	$V_{CC}$	Power supply input
2	$\overline{SR}$	Smart Reset™ button input
3	$V_{REF}$	Precise 1.5 V voltage reference
4	$PS_{HOLD}$	$PS_{HOLD}$ input
5	$C_{SRD}$	Adjustable Smart Reset™ delay time input
6	$\overline{PB}$	Push-button input
7	$\overline{VCC}_{LO}$	Output for high threshold comparator output ( $V_{TH+}$ )
8	$\overline{PB}_{OUT}$	Status of $\overline{PB}$ push-button input
9	EN or $\overline{EN}$	Enable output
10	$\overline{RST}$	Reset output
11	$\overline{INT}$	Interrupt output
12	GND	Ground

Figure 5. TDFN12 pin connections

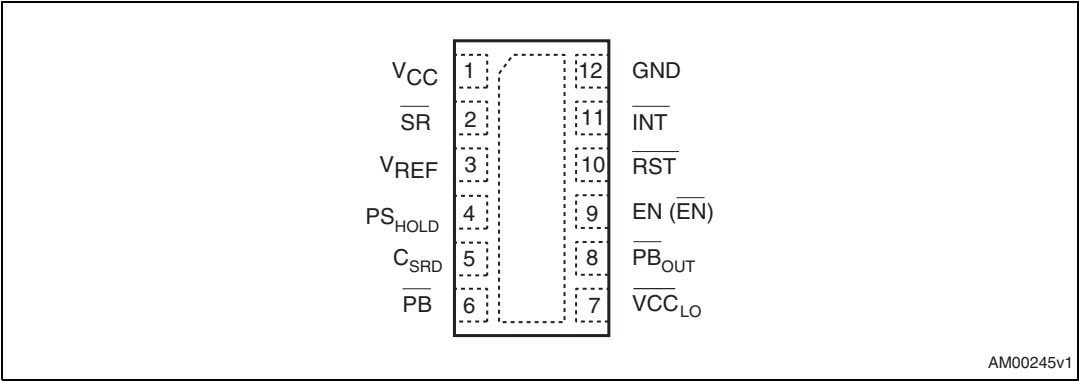
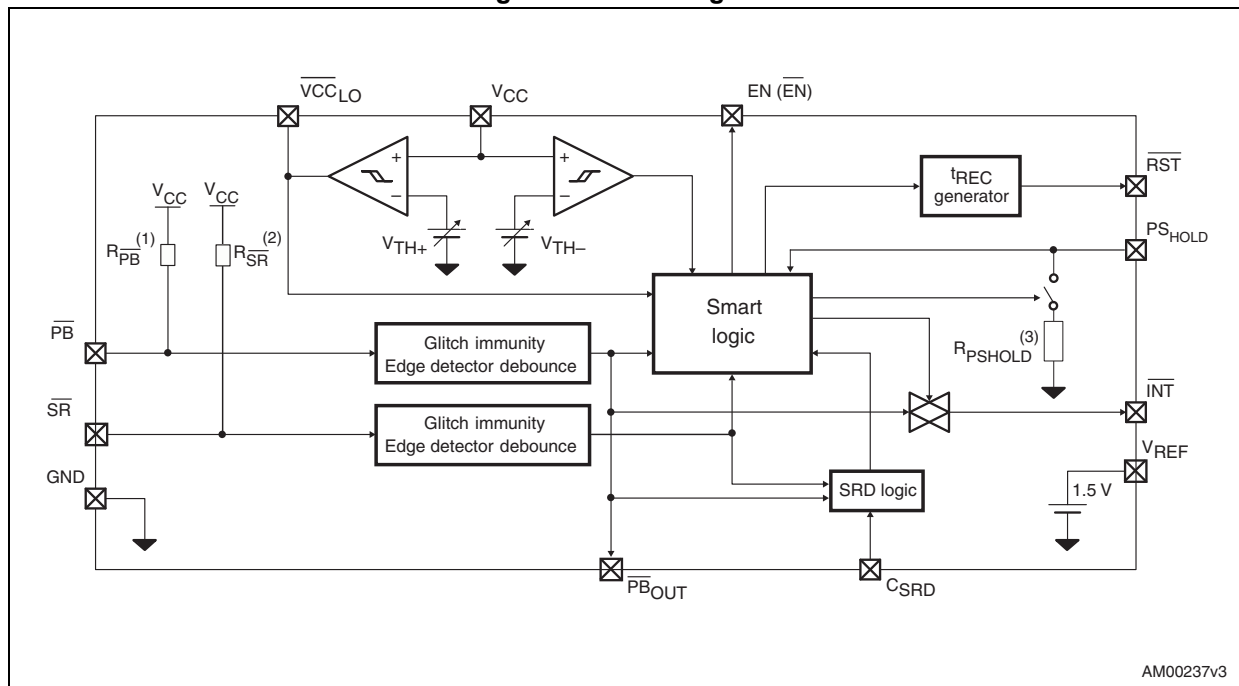




Figure 6. Block diagram



1. Internal pull-up resistor connected to  $\overline{PB}$  input (see [Table 5](#) for precise specifications).
2. Optional internal pull-up resistor connected to  $\overline{SR}$  input (see [Table 5](#) for precise specifications and [Table 10](#) for detailed device options).
3. Internal pull-down resistor is connected to  $PS_{HOLD}$  input only during startup (see [Figure 7](#), [8](#), [9](#), [10](#), [11](#), [12](#), [13](#), and [18](#)).

## 2 Pin descriptions

### **V<sub>CC</sub> - power supply input**

V<sub>CC</sub> is monitored during startup and normal operation for sufficient voltage level. Decouple the V<sub>CC</sub> pin from ground by placing a 0.1 µF capacitor as close to the device as possible.

### **$\overline{\text{SR}}$ - Smart Reset™ button input**

This input is equipped with voltage detector with a factory-trimmed threshold and has ±8 kV HBM ESD protection.

Both  $\overline{\text{PB}}$  and  $\overline{\text{SR}}$  buttons have to be pressed and held for t<sub>SRD</sub> period so the long push is recognized and the reset is asserted (or the enable output is deasserted depending on the option) - see [Figure 15](#), [16](#), and [17](#).

Active low  $\overline{\text{SR}}$  input is usually connected to GND through the momentary push-button (see [Figure 1](#)) and it has an optional 100 kΩ pull-up resistor. It is also possible to drive this input using an external device with either open drain (recommended) or push-pull output. Open drain output can be connected in parallel with push-button or other open drain outputs, which is not possible with push-pull output.  $\overline{\text{SR}}$  input is monitored for falling edge after power-up and must not be grounded permanently.

### **V<sub>REF</sub> - external precise 1.5 V voltage reference**

This 1.5 V voltage reference is specified with very tight accuracy of 1% (see [Table 5](#)). It has proper output voltage as soon as the reset output is deasserted (i.e. after t<sub>REC</sub> expires) and it is disabled when the device enters standby mode. A mandatory capacitor needs to be connected to V<sub>REF</sub> output (even if V<sub>REF</sub> is not used). Capacitor value of 1 µF is recommended.

### **PS<sub>HOLD</sub> input**

This input is equipped with a voltage detector with a factory-trimmed threshold. It is used to confirm correct power-up of the device (if EN or  $\overline{\text{EN}}$  is not asserted) or to initiate a shutdown (if EN or  $\overline{\text{EN}}$  is asserted).

Forcing PS<sub>HOLD</sub> high during power-up confirms the proper start of the application and keeps enable output asserted. Because most processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS<sub>HOLD</sub> input during startup (see [Figure 7](#), [8](#), [9](#), [10](#), [11](#), [12](#), [13](#), and [18](#)).

Forcing the PS<sub>HOLD</sub> signal low during normal operation deasserts the enable output (see [Figure 14](#)). Input voltage on this pin is compared to an accurate voltage reference.

### **C<sub>SRD</sub> - Smart Reset™ delay time input**

A capacitor to ground determines the additional time (t<sub>SRD</sub>) that  $\overline{\text{PB}}$  with  $\overline{\text{SR}}$  must be pressed and held before a long push is recognized. The connected C<sub>SRD</sub> capacitor is charged with I<sub>SRD</sub> current. Additional Smart Reset™ delay time t<sub>SRD</sub> ends when voltage on the C<sub>SRD</sub> capacitor reaches the V<sub>SRD</sub> voltage threshold. It is recommended to use a low ESR capacitor (e.g. ceramic). If the capacitor is not used, leave the C<sub>SRD</sub> pin open. If no capacitor is connected, there is no t<sub>SRD</sub> and a long push is recognized right after t<sub>INT\_Min</sub> expires (see [Figure 18](#) and [19](#)).

**$\overline{\text{PB}}$  - power ON switch**

This input is equipped with a voltage detector with a factory-trimmed threshold and has  $\pm 8$  kV HBM ESD protection.

When the  $\overline{\text{PB}}$  button is pressed and held, the battery voltage is detected and EN (or  $\overline{\text{EN}}$ ) is asserted if the battery voltage is above the threshold  $V_{\text{TH+}}$  during the whole  $t_{\text{DEBOUNCE}}$  period (see [Figure 13](#)).

A short push of the push-button during normal operation can initiate an interrupt through debounced  $\overline{\text{INT}}$  output (see [Figure 14](#)) and a long push of  $\overline{\text{PB}}$  and  $\overline{\text{SR}}$  simultaneously can either assert reset output  $\overline{\text{RST}}$  (see [Figure 18](#)) or deassert the EN or  $\overline{\text{EN}}$  output (see [Figure 19](#)) based on the option used.

*Note: A switch to GND must be connected to this input (e.g. mechanical push-button, open drain output of external circuitry, etc.), see [Figure 1](#). This ensures a proper startup signal on  $\overline{\text{PB}}$  (i.e. a transition from full  $V_{\text{CC}}$  below specified  $V_{\text{IL}}$ ).  $\overline{\text{PB}}$  input has an internal 100 k $\Omega$  pull-up resistor connected.*

 **$\overline{\text{VCC}}_{\text{LO}}$  - high threshold detection output**

During power-up,  $\overline{\text{VCC}}_{\text{LO}}$  is low when  $V_{\text{CC}}$  supply voltage is below the  $V_{\text{TH+}}$  threshold. After successful power-up (i.e. during normal operation)  $\overline{\text{VCC}}_{\text{LO}}$  is low anytime undervoltage is detected (see [Figure 13](#)).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k $\Omega$  is sufficient in most applications.

$\overline{\text{VCC}}_{\text{LO}}$  is floating when STM660x is in standby mode.

 **$\overline{\text{PB}}_{\text{OUT}}$  -  $\overline{\text{PB}}$  input state**

If the push-button  $\overline{\text{PB}}$  is pressed, the pin stays low during the  $t_{\text{DEBOUNCE}}$  time period. If  $\overline{\text{PB}}$  is asserted for the entire  $t_{\text{DEBOUNCE}}$  period,  $\overline{\text{PB}}_{\text{OUT}}$  will then stay low for at least  $t_{\text{INT\_Min}}$ . If  $\overline{\text{PB}}$  is asserted after  $t_{\text{INT\_Min}}$  expires,  $\overline{\text{PB}}_{\text{OUT}}$  will return high as soon as  $\overline{\text{PB}}$  is deasserted (see [Figure 22](#)).  $\overline{\text{PB}}_{\text{OUT}}$  ignores  $\overline{\text{PB}}$  assertion during an undervoltage condition. At startup on the STM6601  $\overline{\text{PB}}_{\text{OUT}}$  will respond only to the first  $\overline{\text{PB}}$  assertion and any other assertion will be ignored until  $t_{\text{ON\_BLANK}}$  expires. This output is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k $\Omega$  is sufficient in most applications.

**EN or  $\overline{\text{EN}}$  - enable output**

This output is intended to enable system power (see [Figure 1](#)). EN is asserted **high** after a valid turn-on event has been detected and confirmed (i.e. push-button has been pressed and held for  $t_{\text{DEBOUNCE}}$  or more and  $V_{\text{CC}} > V_{\text{TH+}}$  voltage level has been detected - see [Figure 13](#)). EN is released **low** if any of the conditions below occur:

- the push-button is released before  $\text{PS}_{\text{HOLD}}$  is driven high (valid for STM6600, see [Figure 9](#)) or  $t_{\text{ON\_BLANK}}$  expires before  $\text{PS}_{\text{HOLD}}$  is driven high during startup (valid for both STM6600 and STM6601, see [Figure 10](#) and [12](#)).
- $\text{PS}_{\text{HOLD}}$  is driven low during normal operation (see [Figure 14](#)).
- an undervoltage condition is detected for more than  $t_{\text{SRD}} + t_{\text{INT\_Min}} + t_{\text{DEBOUNCE}}$  (see [Figure 21](#)).
- a long push of the buttons is detected (only for the device with option “EN deasserted by long push” - see [Figure 19](#)) or  $\text{PS}_{\text{HOLD}}$  is not driven high during  $t_{\text{ON\_BLANK}}$  after a long push of the buttons (only for the device with option “RST asserted by long push” - see [Figure 18](#)).

Described logic levels are inverted in case of  $\overline{\text{EN}}$  output. Output type is push-pull by default.

 **$\overline{\text{RST}}$  - reset output**

This output pulls low for  $t_{\text{REC}}$ :

- during startup.  $\overline{\text{PB}}$  has been pressed (falling edge on the  $\overline{\text{PB}}$  detected) and held for at least  $t_{\text{DEBOUNCE}}$  and  $V_{\text{CC}} > V_{\text{TH+}}$  (see [Figure 7, 8, 9, 10, 11, 12](#) and [13](#) for more details).
- after long push detection (valid only for the device with option “ $\overline{\text{RST}}$  asserted by long push”).  $\overline{\text{PB}}$  has been pressed (falling edge on the  $\overline{\text{PB}}$  detected) and held for more than  $t_{\text{DEBOUNCE}} + t_{\text{SRD}}$  (additional Smart Reset™ delay time can be adjusted by the external capacitor  $C_{\text{SRD}}$ ) - see [Figure 18](#).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k $\Omega$  is sufficient in most applications.

 **$\overline{\text{INT}}$  - interrupt output**

While the system is under normal operation ( $\text{PS}_{\text{HOLD}}$  is driven high, power for application is asserted), the  $\overline{\text{INT}}$  is driven **low** if:

- $V_{\text{CC}}$  falls below  $V_{\text{TH-}}$  threshold (i.e. undervoltage is detected - see [Figure 20](#) and [21](#)).
- the falling edge on the  $\overline{\text{PB}}$  is detected and the push-button is held for  $t_{\text{DEBOUNCE}}$  or more.  $\overline{\text{INT}}$  is driven low after  $t_{\text{DEBOUNCE}}$  and stays low as long as  $\overline{\text{PB}}$  is held. The  $\overline{\text{INT}}$  signal is held high during power-up.

The state of the  $\overline{\text{PB}}_{\text{OUT}}$  output can be used to determine if the interrupt was caused by either the assertion of the  $\overline{\text{PB}}$  input, or was due to the detection of an undervoltage condition on  $V_{\text{CC}}$ .

$\overline{\text{INT}}$  output is asserted low for at least  $t_{\text{INT\_Min}}$ .

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k $\Omega$  is sufficient in most applications.

**GND - ground**

### 3 Operation

The STM6600-STM6601 simplified smart push-button on/off controller with Smart Reset™ and power-on lockout enables and disables power for the application depending on push-button states, signals from the processor, and battery voltage.

#### Power-on

Because most of the processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS<sub>HOLD</sub> input during startup (see [Figure 7](#), [8](#), [9](#), [10](#), [11](#), [12](#), [13](#), and [18](#)).

To power up the device the push-button  $\overline{\text{PB}}$  has to be pressed for at least  $t_{\text{DEBOUNCE}}$  and  $V_{\text{CC}}$  has to be above  $V_{\text{TH+}}$  for the whole  $t_{\text{DEBOUNCE}}$  period. If the battery voltage drops below  $V_{\text{TH+}}$  during the  $t_{\text{DEBOUNCE}}$ , the counter is reset and starts to count again when  $V_{\text{CC}} > V_{\text{TH+}}$  (see [Figure 13](#)). After  $t_{\text{DEBOUNCE}}$  the enable signal is asserted (EN goes high,  $\overline{\text{EN}}$  goes low), reset output  $\overline{\text{RST}}$  is asserted for  $t_{\text{REC}}$  and then the startup routine is performed by the processor. During initialization, the processor sets the PS<sub>HOLD</sub> signal high.

On the STM6600 the PS<sub>HOLD</sub> signal has to be set high prior to push-button release and  $t_{\text{ON\_BLANK}}$  expiration, otherwise the enable signal is deasserted (EN goes low,  $\overline{\text{EN}}$  goes high) - see [Figure 7](#), [8](#), [9](#), and [10](#). The time up to push-button release represents the maximum time allowed for the system to power up and initialize the circuits driving the PS<sub>HOLD</sub> input. If the PS<sub>HOLD</sub> signal is low at push-button release, the enable output is deasserted immediately, thus turning off the system power. If  $t_{\text{ON\_BLANK}}$  expires prior to push-button release, the PS<sub>HOLD</sub> state is checked at its expiration. This safety feature disables the power and prevents discharging the battery if the push-button is stuck or it is held for an unreasonable period of time and the application is not responding (see [Figure 8](#) and [10](#)).  $\overline{\text{PB}}$  status,  $\overline{\text{INT}}$  status and  $V_{\text{CC}}$  undervoltage detection are not monitored until power-up is completed.

On the STM6601 the PS<sub>HOLD</sub> signal has to be set high before  $t_{\text{ON\_BLANK}}$  expires, otherwise the enable signal is deasserted - see [Figure 11](#) and [12](#). In this case the  $t_{\text{ON\_BLANK}}$  period is the maximum time allowed for the power switch and processor to perform the proper power-on. If the PS<sub>HOLD</sub> signal is low at the end of the blanking period, the enable output is released immediately, thus turning off the system power.  $\overline{\text{PB}}$  status,  $\overline{\text{INT}}$  status and  $V_{\text{CC}}$  undervoltage detection are not monitored during the entire  $t_{\text{ON\_BLANK}}$  period. This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.

#### Push-button interrupt

If the device works under normal operation (i.e. PS<sub>HOLD</sub> is high) and the push-button  $\overline{\text{PB}}$  is pressed for more than  $t_{\text{DEBOUNCE}}$ , a negative pulse with minimum  $t_{\text{INT\_Min}}$  width is generated on the INT output. By connecting INT to the processor interrupt input (INT or NMI) a safeguard routine can be performed and the power can be shut down by setting PS<sub>HOLD</sub> low - see [Figure 14](#).

#### Forced power-down mode

The PS<sub>HOLD</sub> output can be forced low anytime during normal operation by the processor and can deassert the enable signal - see [Figure 14](#).

**Undervoltage detection**

If  $V_{CC}$  voltage drops below  $V_{TH}$  voltage threshold during normal operation, the  $\overline{INT}$  output is driven low (see [Figure 20](#) and [Figure 21](#)).

If an undervoltage condition is detected for  $t_{DEBOUNCE} + t_{\overline{INT\_Min}} + t_{SRD}$ , the enable output is deasserted (see [Figure 21](#)).

**Hardware reset or power-down while system not responding**

If the system is not responding and the system hangs, the  $\overline{PB}$  and  $\overline{SR}$  push-buttons can be pressed simultaneously longer than  $t_{DEBOUNCE} + t_{\overline{INT\_Min}} + t_{SRD}$ , and then

- a) either the reset output  $\overline{RST}$  is asserted for  $t_{REC}$  and the processor is reset (valid only for the device with option “ $\overline{RST}$  asserted by long push”) – see [Figure 18](#)
- b) or the power is disabled by EN or  $\overline{EN}$  signal (valid only for the device with option “EN deasserted by long push”) – see [Figure 19](#)

The  $t_{SRD}$  is set by the external capacitor connected to the  $C_{SRD}$  pin.  $\overline{SR}$  input is monitored for falling edge after power-up and must not be grounded permanently.

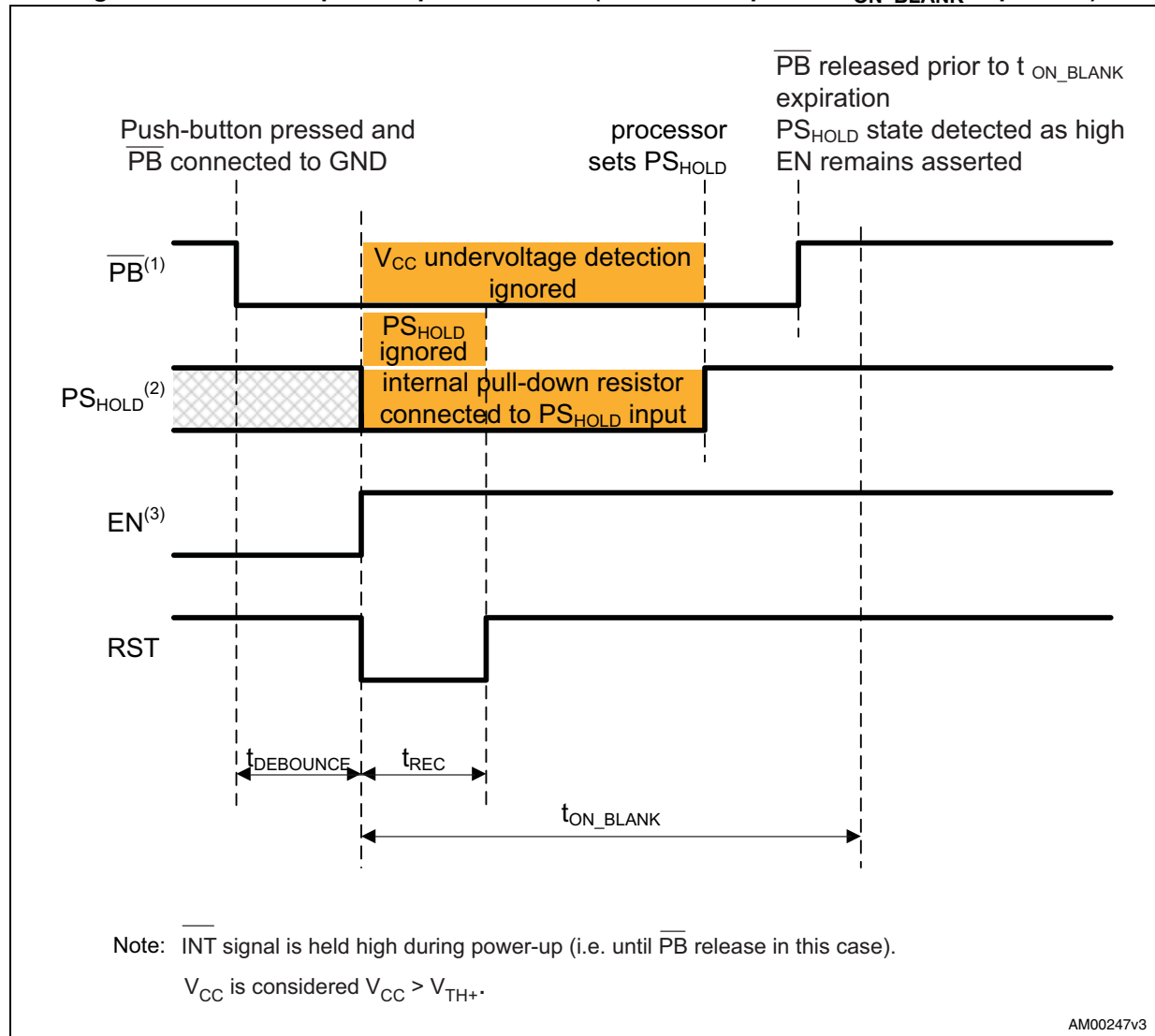
**Standby**

If the enable output is deasserted (i.e. EN is low or  $\overline{EN}$  is high), the STM660x device enters standby mode with low current consumption (see [Table 5](#)). In standby mode  $\overline{PB}$  input is only monitored for the falling edge. The external 1.5 V voltage reference is also disabled in standby mode.

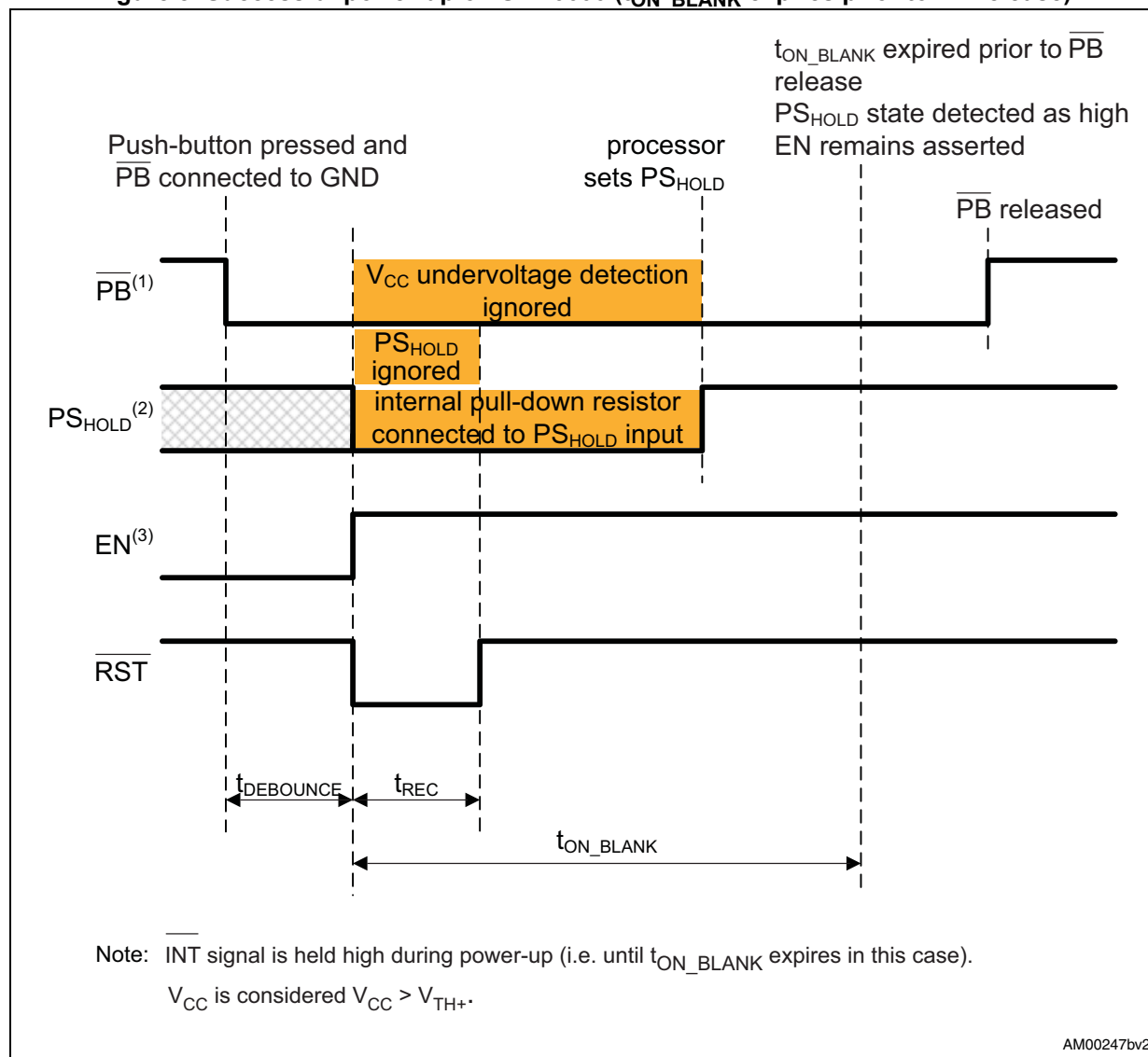


## 4 Waveforms

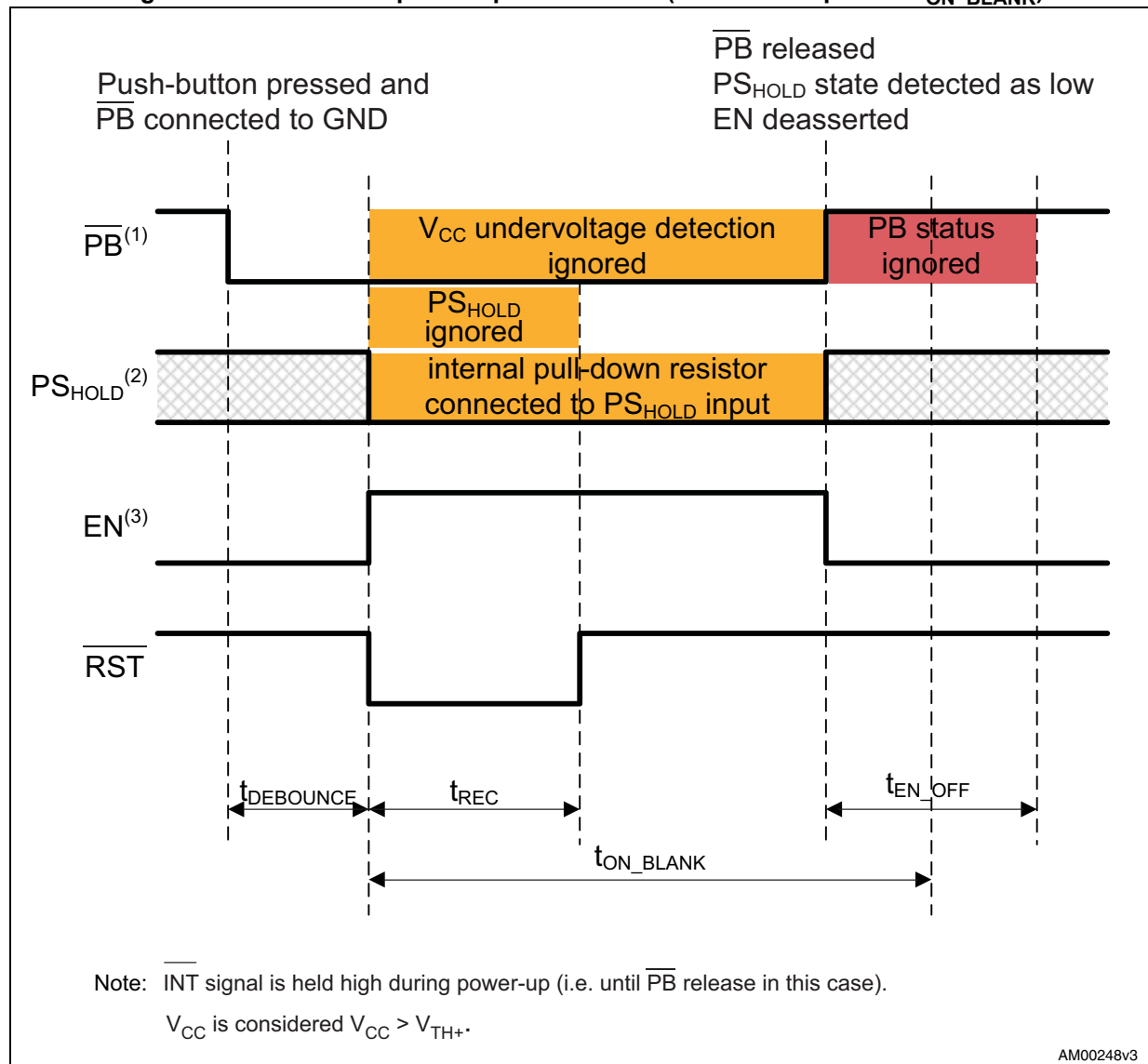
Figure 7. Successful power-up on STM6600 ( $\overline{\text{PB}}$  released prior to  $t_{\text{ON\_BLANK}}$  expiration)



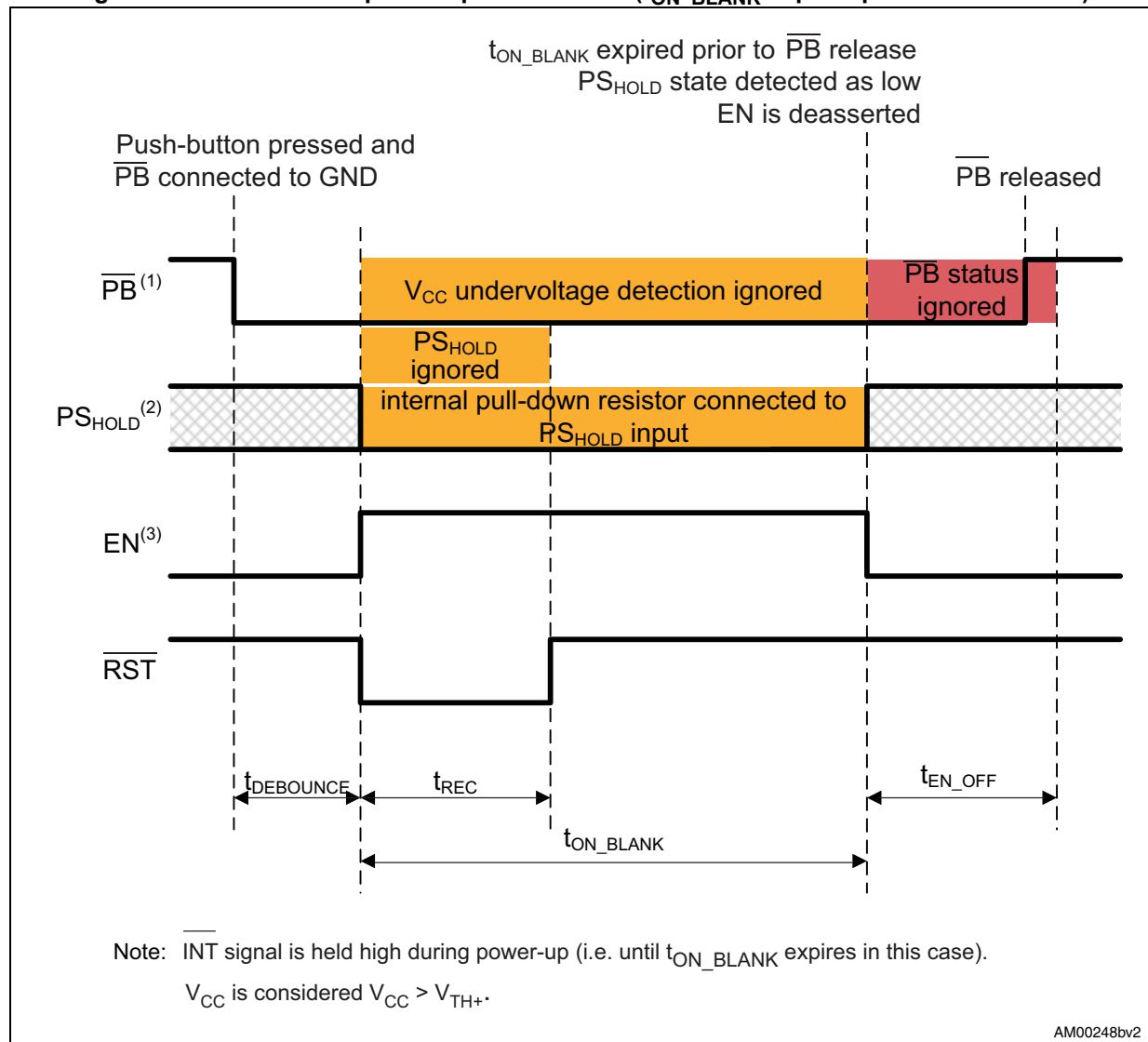
1.  $\overline{\text{PB}}$  detection on falling and rising edges.
2. Internal pull-down resistor 300 k $\Omega$  is connected to  $\text{PS}_{\text{HOLD}}$  input during power-up.
3. EN signal is high even after  $\overline{\text{PB}}$  release, because processor sets  $\text{PS}_{\text{HOLD}}$  signal high before  $\overline{\text{PB}}$  is released.

Figure 8. Successful power-up on STM6600 ( $t_{ON\_BLANK}$  expires prior to  $\overline{PB}$  release)

1.  $\overline{PB}$  detection on falling and rising edges.
2. Internal pull-down resistor 300 k $\Omega$  is connected to  $PS_{HOLD}$  input during power-up.
3.  $t_{ON\_BLANK}$  expires prior to  $\overline{PB}$  release so  $PS_{HOLD}$  is checked at its expiration.

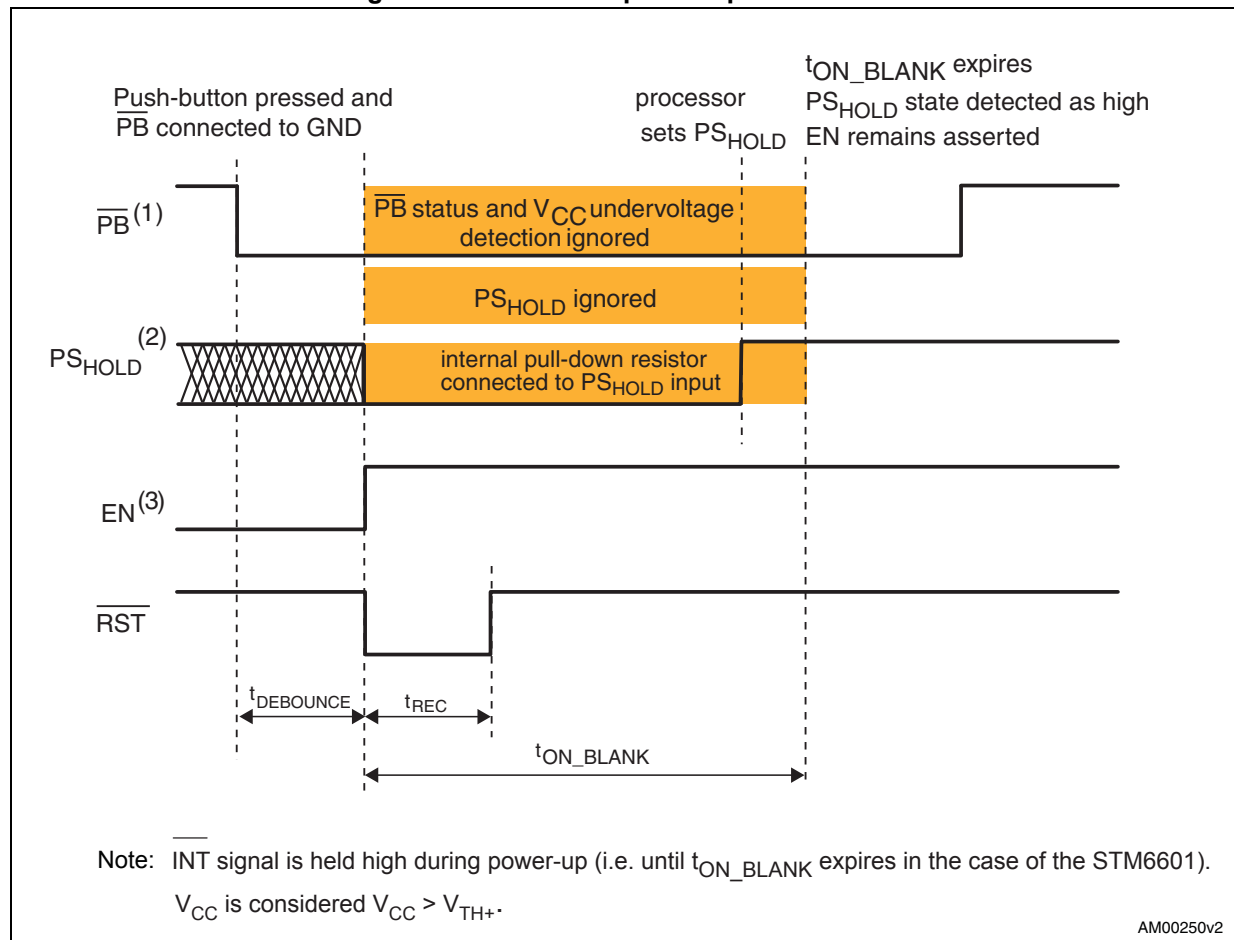
Figure 9. Unsuccessful power-up on STM6600 ( $\overline{\text{PB}}$  released prior to  $t_{\text{ON\_BLANK}}$ )

1.  $\overline{\text{PB}}$  detection on falling and rising edges.
2. Internal pull-down resistor 300 k $\Omega$  is connected to PS\_HOLD input during power-up.
3. EN signal goes low with  $\overline{\text{PB}}$  release, because processor did not force PS\_HOLD signal high.

Figure 10. Unsuccessful power-up on STM6600 ( $t_{ON\_BLANK}$  expires prior to  $\overline{PB}$  release)

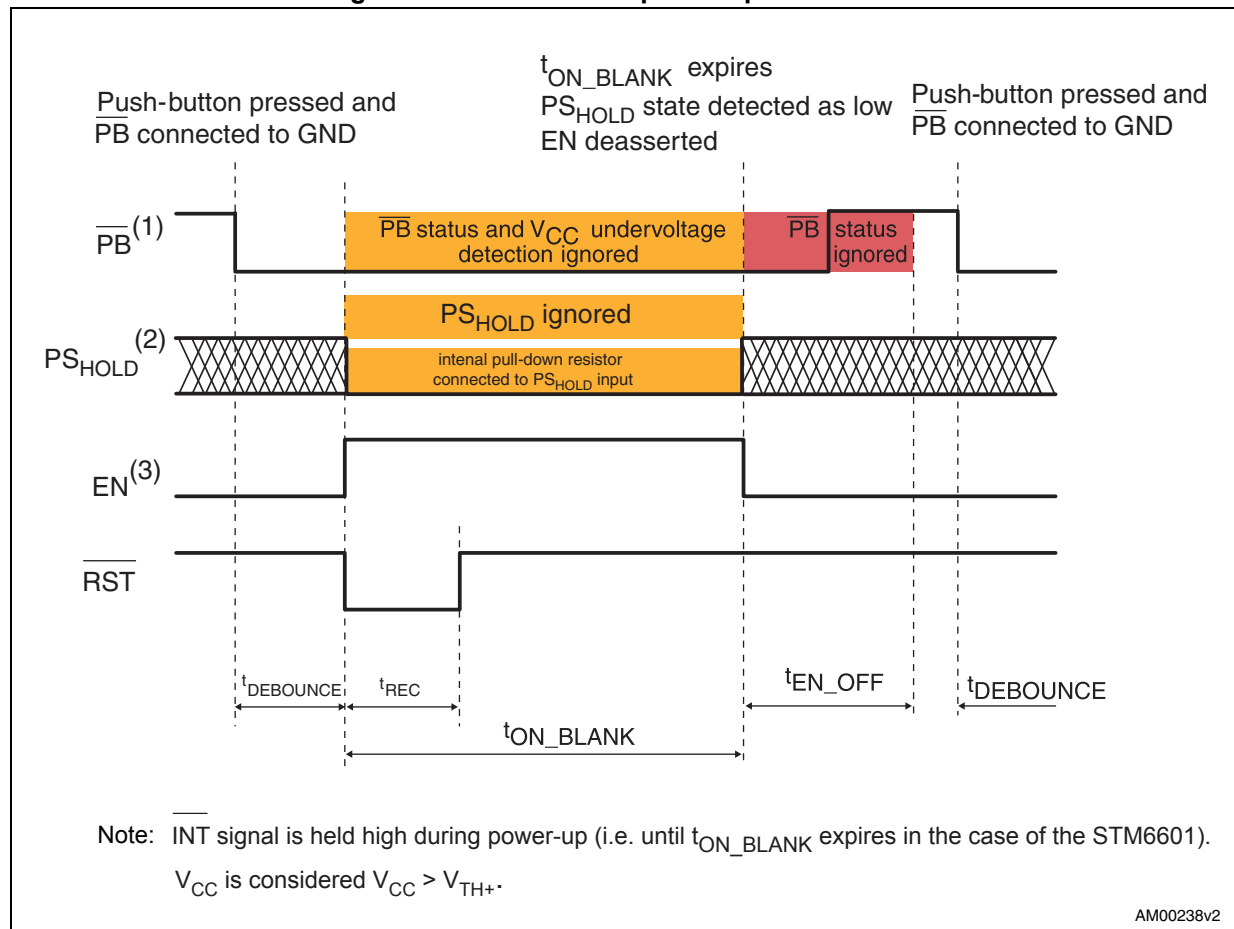
1.  $\overline{PB}$  detection on falling and rising edges.
2. Internal pull-down resistor 300 k $\Omega$  is connected to  $PS_{HOLD}$  input during power-up.
3.  $t_{ON\_BLANK}$  expires prior to  $\overline{PB}$  release so  $PS_{HOLD}$  is checked at its expiration.

Figure 11. Successful power-up on STM6601



1.  $\overline{PB}$  detection on falling edge.
2. Internal pull-down resistor 300 k $\Omega$  is connected to  $PS_{HOLD}$  input during power-up.
3.  $PS_{HOLD}$  signal is ignored during  $t_{ON\_BLANK}$ . When  $t_{ON\_BLANK}$  expires, the level of the  $PS_{HOLD}$  signal is high therefore the  $EN$  signal remains asserted.

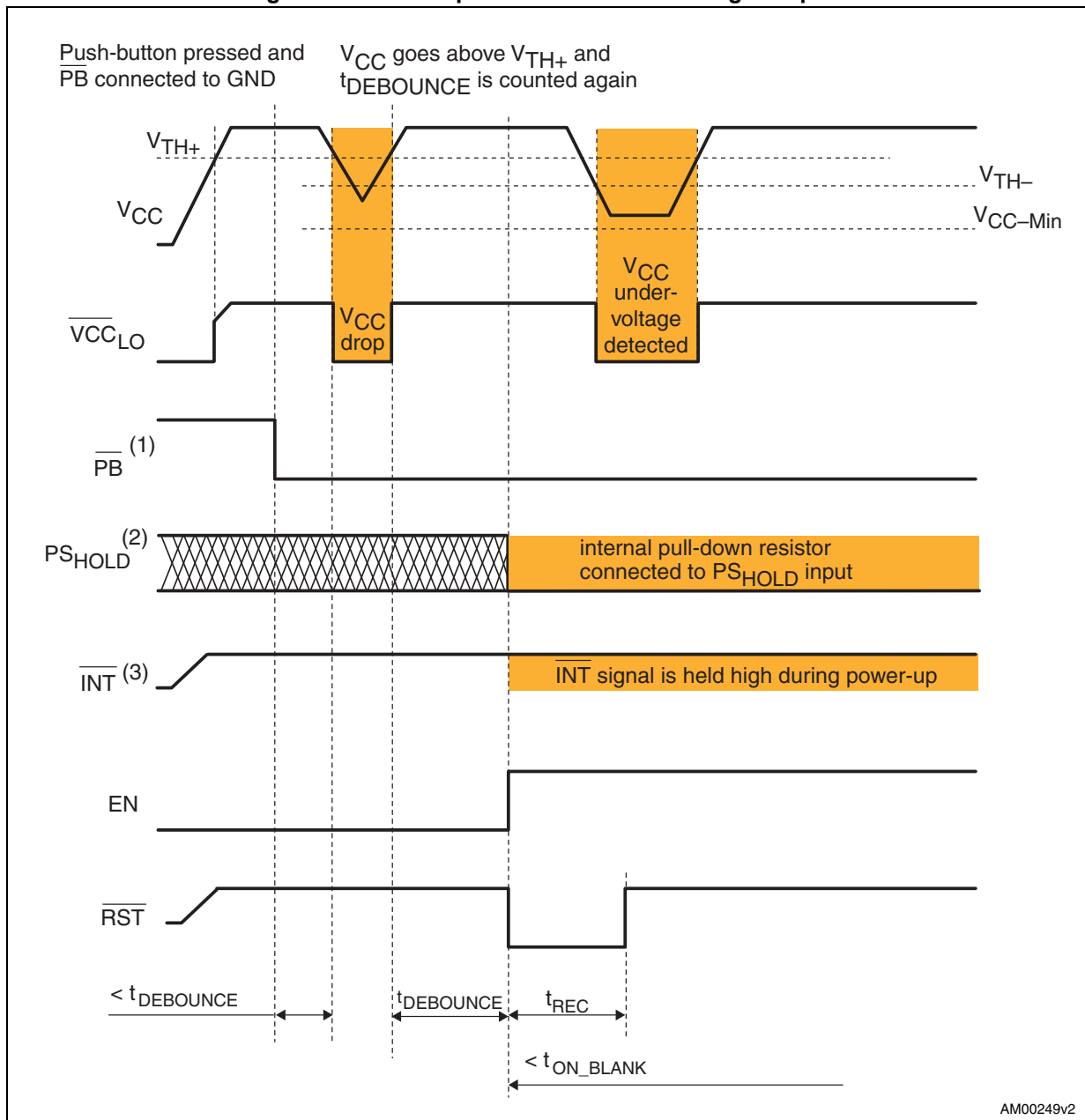
### Figure 12. Unsuccessful power-up on STM6601



1.  $\overline{\text{PB}}$  detection on falling edge.
2. Internal pull-down resistor 300 k $\Omega$  is connected to PS<sub>HOLD</sub> input during power-up.
3. PS<sub>HOLD</sub> signal is ignored during t<sub>ON, BLANK</sub>. When t<sub>ON, BLANK</sub> expires, the level of the PS<sub>HOLD</sub> signal is not high therefore the EN signal goes low. Even releasing the  $\overline{\text{PB}}$  button after the t<sub>ON, BLANK</sub> will not prevent this.

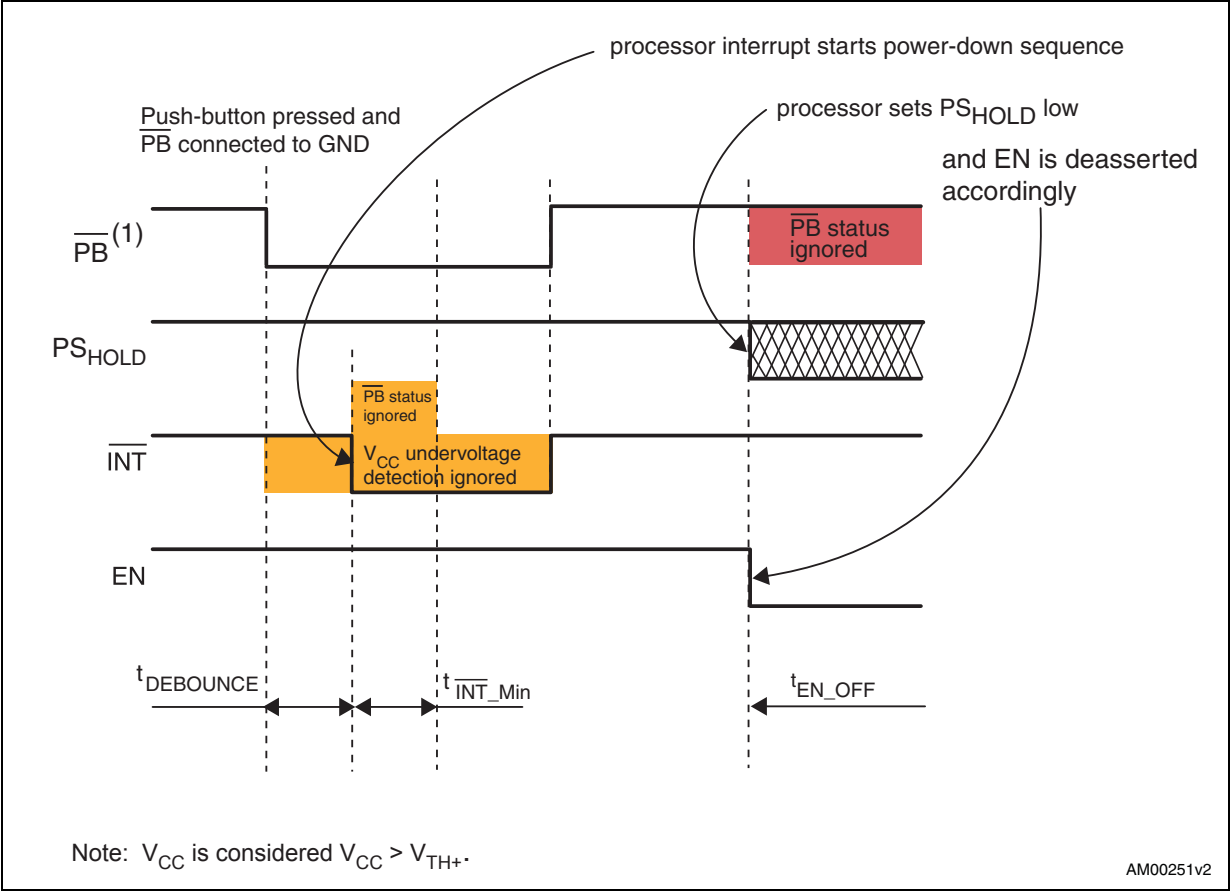


Figure 13. Power-up on STM660x with voltage dropout



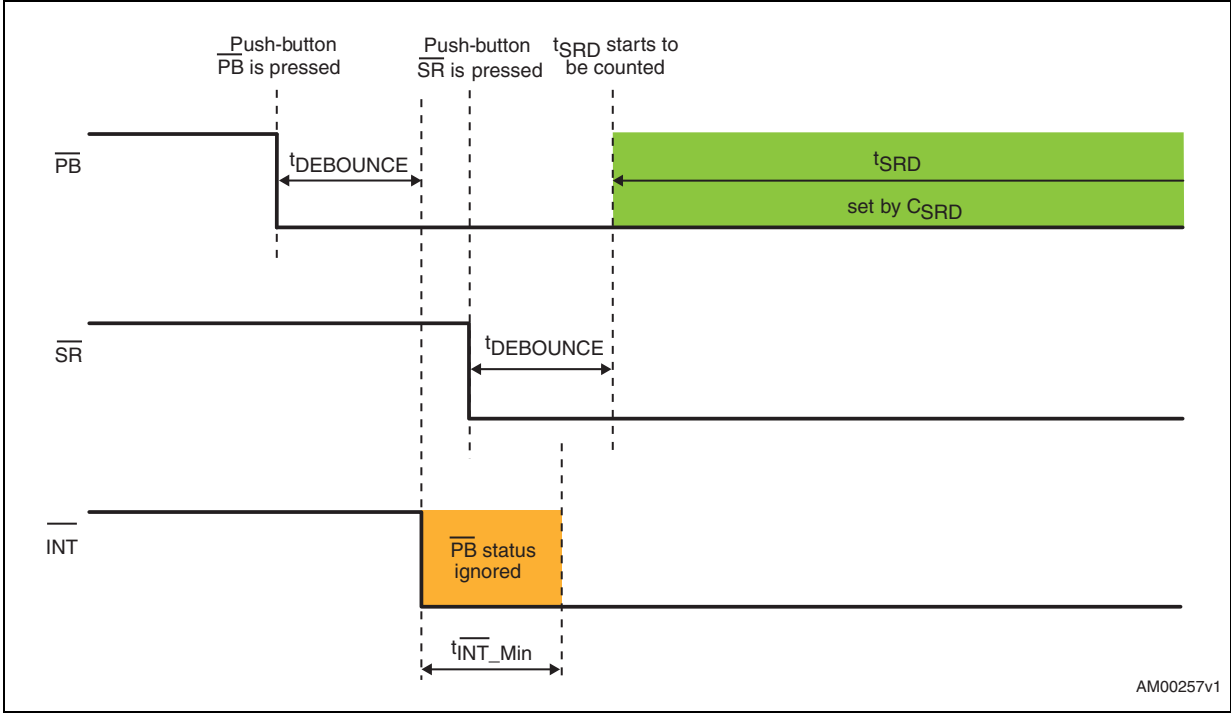
1.  $\overline{\text{PB}}$  detection on falling and rising edges.
2. Internal pull-down resistor 300 k $\Omega$  is connected to  $\text{PS}_{\text{HOLD}}$  input during power-up.
3.  $\overline{\text{INT}}$  signal is held high during power-up.

Figure 14.  $\overline{\text{PB}}$  interrupt



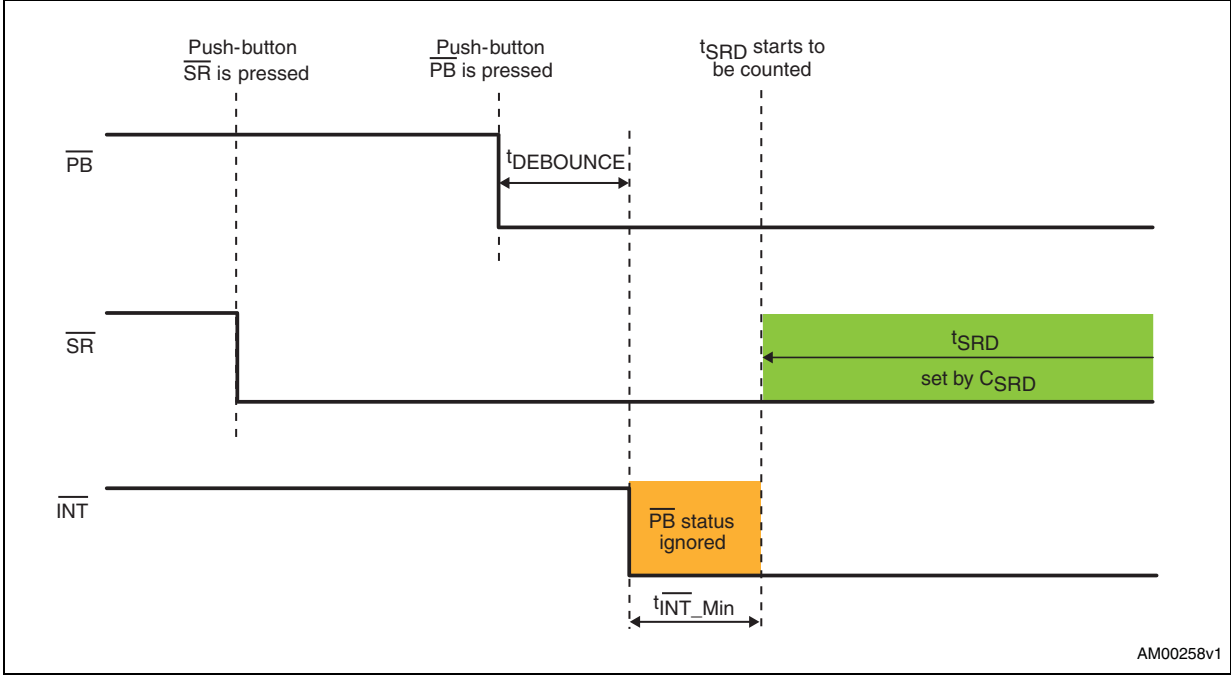
1.  $\overline{\text{PB}}$  detection on falling edge.

Figure 15. Long push,  $\overline{\text{PB}}$  pressed first



AM00257v1

Figure 16. Long push,  $\overline{\text{SR}}$  pressed first



AM00258v1

Figure 17. Invalid long push

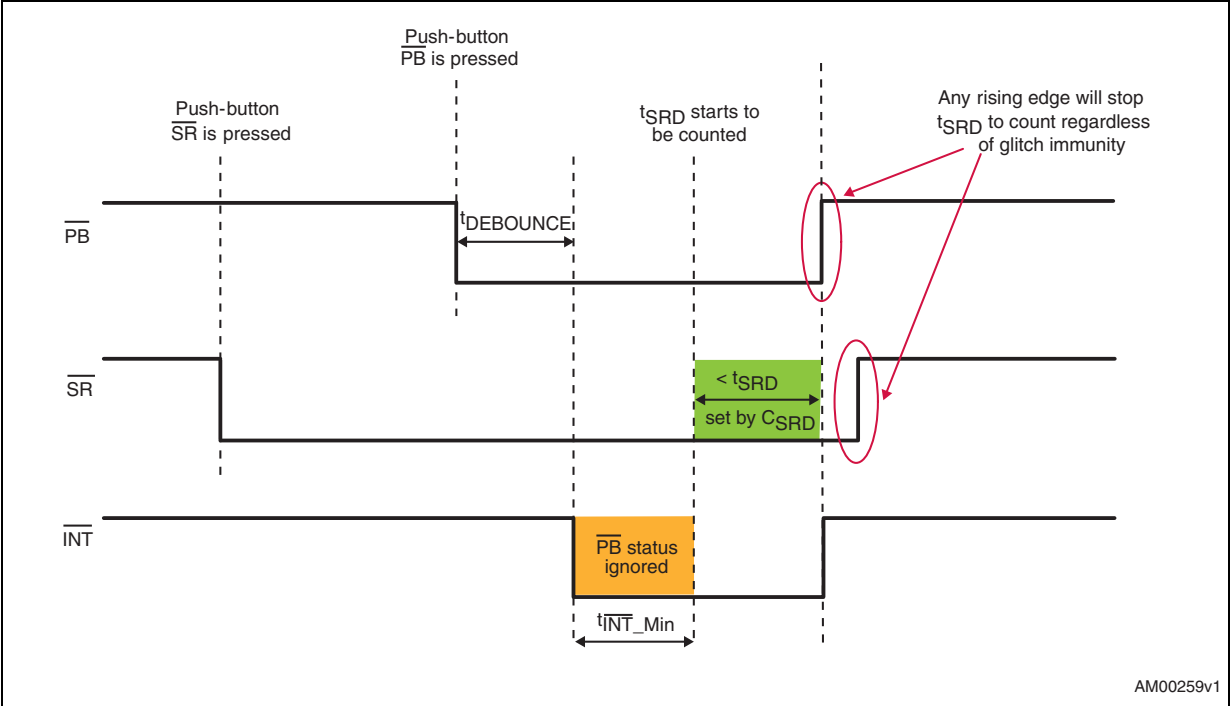
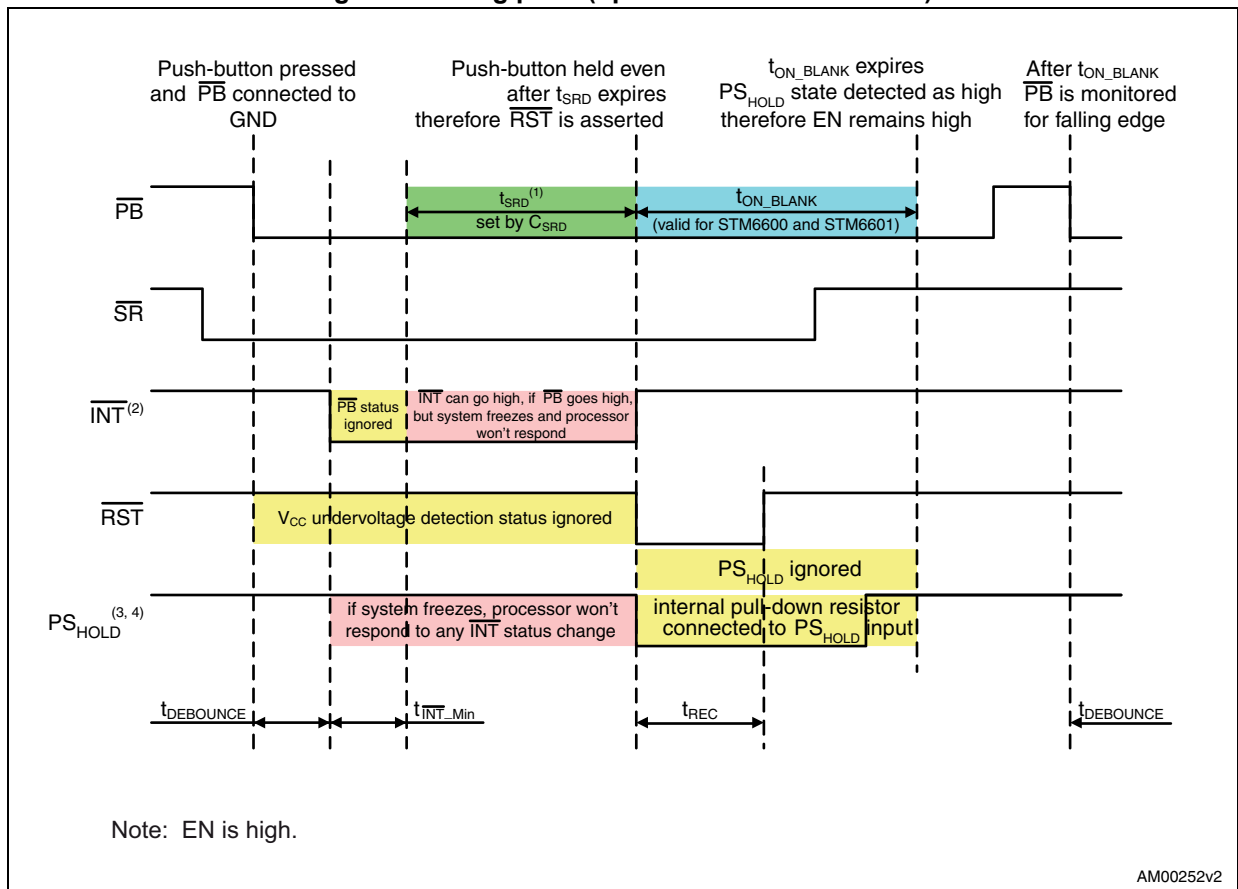
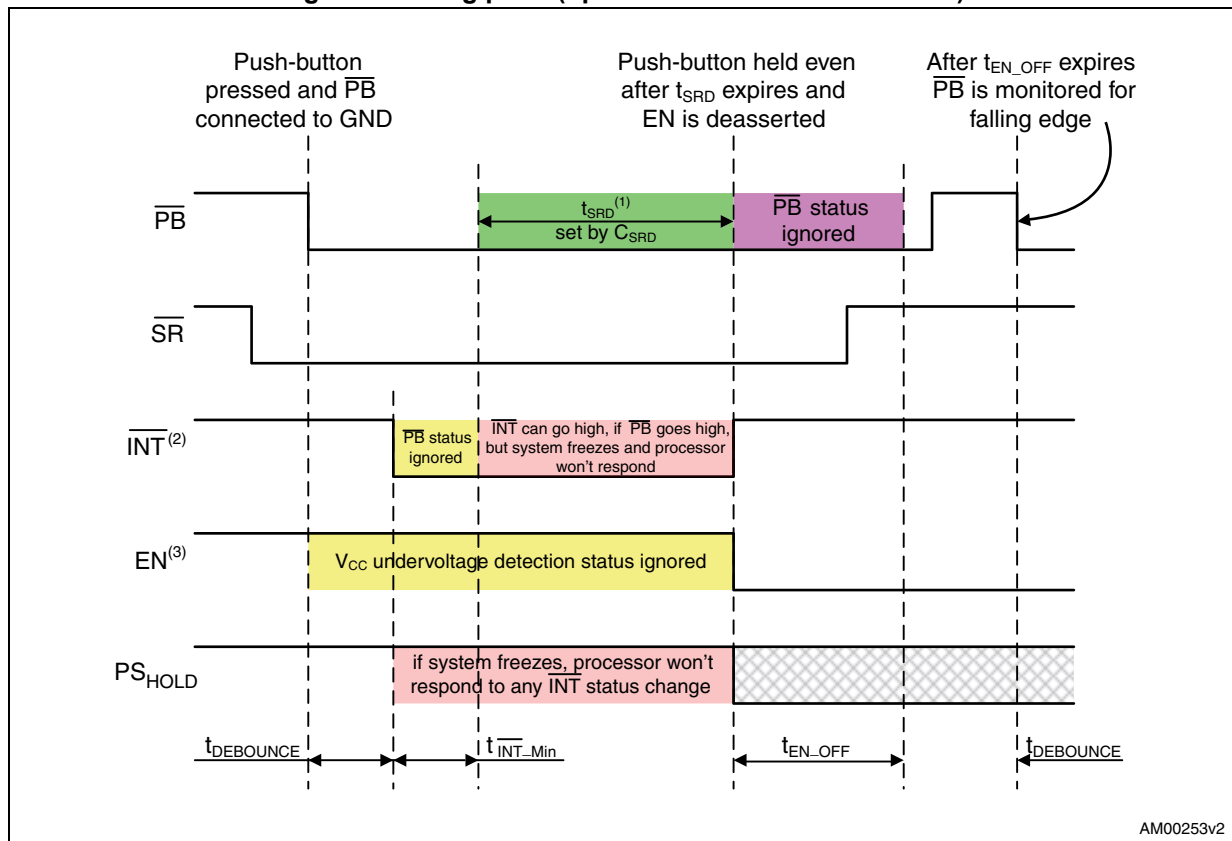


Figure 18. Long push (option with  $\overline{\text{RST}}$  assertion)

1.  $t_{\text{SRD}}$  period is set by external capacitor  $C_{\text{SRD}}$ .
2.  $\overline{\text{PB}}$  ignored during  $t_{\text{INT\_Min}}$ .
3.  $\text{PS}_{\text{HOLD}}$  signal is ignored during  $t_{\text{ON\_BLANK}}$ . Its level is checked after  $t_{\text{ON\_BLANK}}$  expires and if it is high the EN signal remains asserted, otherwise EN goes low.
4. Internal pull-down resistor 300 k $\Omega$  is connected to  $\text{PS}_{\text{HOLD}}$  input during startup when device is reset.

Figure 19. Long push (option with enable deassertion)



1.  $t_{SRD}$  period is set by external capacitor  $C_{SRD}$ .
2.  $\overline{PB}$  ignored during  $t_{INT\_Min}$ .
3. After  $t_{SRD}$  expires EN is forced low.